Crystal oscillator

Epson Toyocom

(Unit:mm)



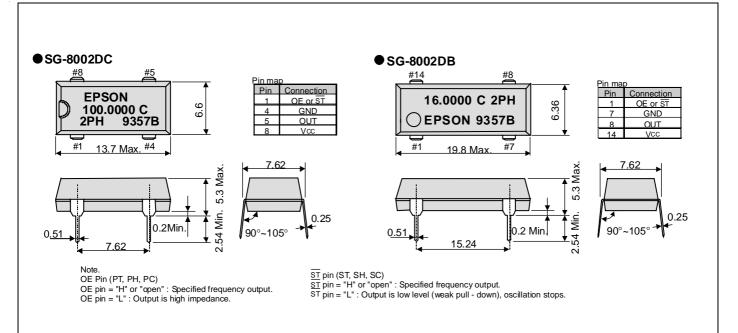
ltem		Symbol	Specifications *2			Remarks	
			PT / ST	PH/SH	PC / SC	INCITIALING	
Output frequency range			1 MHz to 125 MHz		_	Vcc=4.5 V to 5.5 V	
		fo			1 MHz to 125 MHz	Vcc=3.0 V to 3.6 V	
			— 1 MHz to		1 MHz to 66.7 MHz	Vcc=2.7 V to 3.6 V	
Supply voltage		Vcc	4.5 V to 5.5 V 2.7 V to 3		2.7 V to 3.6 V		
Storage Temperature temperature		T_stg	-55 °C to +125 °C			Store as bare product after unpacking	
range	Operating temperature	T_use	-20 °C to +70 °C (-40 °C to +85 °C)			Refer to "Outline specifications" (Frequency range)	
Frequency tole	2000	f tol	B: ±50 × 10 ⁻⁶ ,C: ±100 × 10 ⁻⁶			-20 °C to +70 °C	
Frequency tole	ance	1_101	M: ±100 × 10 ⁻⁶			-40 °C to +85 °C *3	
Current consur	nption	lcc	45 mA Max. 28 mA Max.		28 mA Max.	No load condition, Max. frequency	
Disable current		I_dis	30 mA Max. 16 mA Max.		16 mA Max.	OE=GND(PT,PH,PC)	
Stand-by current		I_std	50 μA Max.			<u>ST</u> =GND(ST,SH,SC)	
Cummenter 1		SYM			to 60 %	CMOS load:50%Vcc level, Max. load condition	
Symmetry *1		STIVI	40 % to 60 %		_	TTL load: 1.4 V level, Max. load condition	
High output voltage		Voн		Vcc-0.4 V Min.		IOH=-16 mA(PT,ST,PH,SH),-8 mA(PC,SC)	
Low output vol		Vol		0.4 V Max.		loL=16 mA(PT,ST,PH,SH), 8 mA(PC,SC)	
Output load co	ndition (TTL) *1	L_TTL	5 TTL Max.	-	_	Max. frequency and	
Output load condition (CMOS) *1		L_CMOS	15 pF Max.	25 pF Max.	15 pF Max.	Max. supply voltage	
Output enable /		VIH	2.0 V	2.0 V Min. 70		ST terminal or OE terminal	
disable input voltage		VIL	0.8 V	' Max.	20 % Vcc Max.		
Rise time / Fall time *1		tr / tr	- 3 ns Max.		Max.	CMOS load: 20 % Vcc to 80 % Vcc level	
		u / u	4 ns Max. —			TTL load: 0.4 V to 2.4 V level	
Start-up time		t_str	10 ms Max.			Time at minimum supply voltage to be 0 s	
Frequency aging		f_aging	$\pm 5 \times 10^{-6}$ / year Max.			+25 °C, Vcc=5.0 V/ 3.3 V (PC/SC) First year	

Operating temperature (-40 °C to +85 °C), the available frequency, symmetry and output load conditions, please refer to "Outline specifications" page. PLL-PLL connection & Jitter specification, please refer to "Jitter specifications and characteristics chart" page.

*2

PT/ST and PH/SH for "M" tolerance will be available up to 55 MHz. *3 Checking possible by the Frequency Checking Program.

External dimensions



http://www.dgkjly.com



SG-8002 Series_ Outline of specifications

ltem Model		Current Consump tion	Supply Voltage	Output load condition	Output rise time Output fall time	Symmetry	Function	
P SG-8002LB S		30 m.A Max.	4.5 V to 5.5 V	15 pF	3.0 ns Max. (20 % Vcc to 80 % Vcc,L_CMOS=Max.)	40 % to 60 %(50 % V∞, L_CMOS=15 pF, f∞s80 MHz/-40 °C to+85 °C)	OE ST	
(SOJ 4-pin)	PC SC	28 m.A Max.	3.0 V to 3.6 V (2.7 V to 3.6 V)	15 pF	3.0 ns Max. (20 % Vcc to 80 % Vcc, L_CMOS=Max.)	45 % to 55 %(50 % Vcc, L_CMOS=15 pF, Vcc=3.0 V to 3.6 V, f₀≤40 MHz) 40 % to 60 %(50 % Vcc, L_CMOS=15 pF, Vcc=3.0 V to 3.6 V, f₀≤125 MHz) ↑ (50 % Vcc, L_OMOS=15 pF, Vcc=2.7 V to 3.6 V, f₀≤6.7 MHz)	OE ST	
SG-8002CA (SON)	РТ			5 TTL+15 pF (fo≤125 MHz/-20 °C to+70 °C) 25 pF (fo≤66.7 MHz/-20 °C to+70 °C) 5 TTL+15 pF (fo≤40 MHz/-40 °C to +85 °C)	2.0 ns Max. (0.8 V to 2.0 V,L_CMOS or L_TTL=Max.) 4.0 ns Max.	45 % to 55 %(1.4 V, L_TTL=5 TTL+15 pF, f∞≤6.7 MHz/-20 °C to +70 °C) ↑ (1.4 V, L_TTL=5 TTL+15 pF, f∞≤40.0 MHz/-40 °C to +85 °C) 40 % to 60 %(1.4 V, L_TTL=5 TTL+15 pF, f∞≤125 MHz/-20 °C to +70 °C)	OE	
SG-8002JA (SOJ 4-pin)	ST PH	45 mA Max. 4.5 V to 5.5 V		15 pF(f₀≤55 MHz/-40 °C to +85 °C) 25 pF (f₀≤125 MHz/-20 °C to +70 °C)	(0.4 V to 2.4 V,L_CMOS or L_TTL=Max.) 3.0 ns Max.	↑ (1.4 V, L_CMOS=25 pF, f∞56.7 MHz/-20 °C to +70 °C) ↑ (1.4 V, L_CMOS=15 pF, f∞55.0 MHz/-40 °C to +85 °C) 45 % to 55 %(50 % V∞, L_CMOS=25 pF, f∞56.7 MHz/-20 °C to +70 °C) 65 % V∞, L_CMOS=25 pF, f∞56.7 MHz/-20 °C to +70 °C)	ST OE	
SG-8002DB (DIP 14-pin)	SH	-		50 pF (fi≤66.7 MHz/-20 °C to+70 °C) 15 pF (fi≤55 MHz/-40 °C to+85 °C) 25 pF (fi≤40 MHz/-40 °C to+85 °C)	(20 % Vcc to 80 % Vcc,L_CMOS≤25) 4.0 ns Max. (20 % Vcc to 80 % Vcc,L_CMOS=Max.)			
SG-8002DC (DIP 8-pin)	PC SC	28 m.A Max.	3.0 V to 3.6 V (2.7 V to 3.6 V)	15 pF (fi∞66.7 MHz/2.7 to 3.6 V) 15 pF (fi∞125 MHz/3.0 to 3.6 V) 30 pF (fi∞40 MHz/3.0 to 3.6 V)	3.0 ns Max. (20 % Vcc to 80 % Vcc,L_CMOS≤15) 4.0 ns Max.	45 % to 55 %(50 % Vcc, L_CMOS=30 pF, Vcc=3.0 V to 3.6 V, f₀≤40 MHz) 40 % to 60 %(50 % Vcc, L_CMOS=15 pF, Vcc=3.0 V to 3.6 V, f₀≤125 MHz) ↑ (50 % Vcc, L_CMOS=15 pF, Vcc=2.7 V to 3.6 V, f₀≤6.7 MHz)	OE ST	
	PT			5TTL + 15 pF (fo≤90 MHz/-20 to+70 °C) 15 pF (fo≤125 MHz/-20 °C to +70 °C)	(20 % V∞ to 80 % V∞,L_CMOS=Max.) 2.0 ns Max. (0.8 V to 2.0 V,L_CMOS or L_TTL=Max.)	% to 55 %(1.4 V,L_TTL=5 TTL+15 pF, fi∞66.7 MHz/-20 °C to+70 °C) % to 60 %(1.4 V,L_TTL=5 TTL+15 pF, fi∞90.0 MHz/-20 °C to+70 °C)	OE	
SG-8002JC	ST PH	45 mA Max. 4.5 V to 5.5 V	25 pF (fo≤66.7 MHz/-20 °C to+70 °C) 15 pF (fo≤125 MHz/-20 °C to+70 °C)	4.0 ns Max. (0.4 V to 2.4 V,L_CMOS or L_TTL=Max.) 3.0 ns Max.	↑ (1.4 V,L_CMOS=25 pF, fas66.7 MHz/-20 °C to +70 °C) ↑ (1.4 V,L_CMOS=15 pF, fas125 MHz/-20 °C to +70 °C) 45 % to 55 %(50 % Voc, L_CMOS=25 pF, fas66.7 MHz/-20 °C to +70 °C)			
(SOJ 4-pin)	SH			25 pF (fs≤90 MHz/-20 °C to+70 °C) 50 pF (fs≤66.7 MHz/-20 °C to+70 °C)	(20 % V∞ to 80 % V∞,L_CMOS≤25) 4.0 ns Max. (20 % V∞ to 80 % V∞,L_CMOS=Max.)	40 % to 60 %(50 % Vcc, L_CMOS=15 pF, fc≤125 MHz/-20 °C to +70 °C) ↑ (50 % Vcc, L_CMOS=25 pF, fc≤90 MHz/-20 °C to +70 °C) ↑ (50 % Vcc, L_CMOS=50 pF, fc≤50 MHz/-20 °C to +70 °C)		
	PC SC	28 m.A Max.	3.0 V to 3.6 V (2.7 V to 3.6 V)	15 pF (fc≤66.7 MHz/2.7 to 3.6 V) 15 pF (fc≤125 MHz/3.0 to 3.6 V) 30 pF (fc≤40 MHz/3.0 to3.6 V)	3.0 ns Max. (20 % V∞ to 80 % V∞, L_OMOS≤15) 4.0 ns Max. (20 % V∞ to 80 % V∞, L_CMOS=Max.)	45 % to 55 %(50 % Vcc, L_CMOS=30 pF, Vcc=3.0 V to 3.6 V, fa≤40 MHz) 40 % to 60 %(50 % Vcc, L_CMOS=15 pF, Vcc=3.0 V to 3.6 V, fa≤125 MHz) ↑ (50 % Vcc, L_CMOS=15 pF, Vcc=2.7 V to 3.6 V, fa≤6.7 MHz)	OE ST	
SG-8002JF (SOJ 4-pin)	PT	-		15 pF (fi∞≤125 MHz/-20 °C to +70 °C) 25 pF (fi∞≤66.7 MHz/-20 °C to+70 °C) 5TTL + 15 pF (fi∞≤ 90 MHz/-20 °C to +70 °C)	2.0 ns Max. (0.8 V to 2.0 V,L_CMOS≤25) 4.0 ns Max.	45 % to 55 %(1.4 V, L_TTL=5 TTL+15 pF, f∞56.7 MHz/-20 °C to+70 °C) 40 % to 60 %(1.4 V, L_TTL=5 TTL+15 pF, f∞90 MHz/-20 °C to+70 °C) ↑ (1.4 V, L_CMOS=25 pF, f∞56.7 MHz/-20 °C to +70 °C)	OE	
	ST PH	45 m.A Max.	45 m A 4.5 V to 5.5 V	15 pF (f₀≤40 MHz/-40 °C to +85 °C) 15 pF (f₀≤125 MHz/-20 °C to +70 °C)	(0.4 V to 2.4 V,L_CMOS or L_TTL=Max.) 3.0 ns Max.	↑ (1.4 V, L_CMOS=15 pF, fc≤125 MHz/-20 °C to +70 °C) ↑ (1.4 V, L_CMOS=15 pF, fc≤40 MHz/-40 °C to +85 °C) 45 % to 55 %(50 % Voc, L_CMOS=25 pF, fc≤60.7 MHz/-20 °C to +70 °C) 40 % to 60 %(50 % Voc, L_CMOS=25 pF, fc≤90.0 MHz/-20 °C to +70 °C)		
	SH			25 pF (fi≤90 MHz/-20 °C to+70 °C) 50 pF (fi≤50 MHz/-20 °C to+70 °C) 15 pF (fi≤40 MHz/-40 °C to+85 °C)	(20 % Vcc to 80 % Vcc,L_CMOS≤25) 4.0 ns Max. (20 % Vcc to 80 % Vcc,L_CMOS=Max.)	↑ (50 % Voc, L_CMOS=50 pF, fi≤50.0 MHz/-20 °C to+70 °C) ↑ (50 % Voc, L_CMOS=50 pF, fi≤50.0 MHz/-20 °C to+70 °C) ↑ (50 % Voc, L_CMOS=15 pF, fi≤420 MHz/-20 °C to+70 °C) ↑ (50 % Voc, L_CMOS=15 pF, fi≤40 MHz/-40 °C to+85 °C)		
	PC SC	28 m.A Max.	3.0 V to 3.6 V (2.7 V to 3.6 V)	15 pF(fi≪66.7 MHz/2.7 to 3.6 V) 15 pF(fi≪125 MHz/3.0 to 3.6 V) 30 pF(fi≪40 MHz/3.0 to 3.6 V)	3.0 ns Max. (20 % V∞ to 80 % V∞,L_CMOS≤15) 4.0 ns Max.	45 % to 55 %(50 % Vcc, CL=30 pF, Vcc=3.0 V to 3.6 V, fc≤40 MHz) 40 % to 60 %(50 % Vcc, CL=15 pF, Vcc=3.0 V to 3.6 V, fc≤125 MHz) ↑ (50 % Vcc, CL=15 pF, Vcc=2.7 V to 3.6 V, fc≤66.7 MHz)	OE ST	
SG-8002CE (SON)	PT	-		5 TTL+15 pF (fi≤125 MHz/-20 °C to + 70 °C) 5 TTL+15 pF (fi≤27 MHz/-40 °C to +85 °C)	(20 % V∞ to 80 % V∞,L_OMOS=Max.) 2.0 ns Max. (0.8 V to 2.0 V,L_TTL=Max.) 4.0 ns Max.	45 % to 55 %(1.4 V, L_TTL=5 TTL+15 pF, fi≤86.7 MHz/-20 °C to +70 °C) ↑ (1.4 V, L_TTL=5 TTL+15 pF, fi≤27.0 MHz/-40 °C to + 85 °C) 40 % to 60 %(1.4 V, L_TTL=5 TTL+15 pF, fi≤125 MHz/-20 °C to +70 °C)	OE	
	ST PH SH	40 m.A Max.	4.5 V to 5.5 V	511L+15pF (1∞27 MHZ/-40 ℃ 10 +65 ℃) 15pF (1∞125 MHZ/-20 °C to +70 °C) 25pF (1∞27 MHZ/-20 °C to +70 °C) 25pF (1∞27 MHZ/-40 °C to +85 °C)	4.0 n S Max. (0.4 V to 2.4 V,L_TTL=Max.) 3.0 n S Max. (20 % V∞ to 80 % V∞,L_CMOS=Max.)	40 % to 50 %(1.4 V, L_11 L=5 11L+15 pF, 1∞125 MHZ/-20 °C to +70 °C) 45 % to 55 %(50 % V∞, L_CMOS=25 pF, f∞86.7 MHZ/-20 °C to +70 °C) 1 (50 % V∞, L_CMOS=25 pF, f∞27.0 MHz/-40 °C to +85 °C) 40 % to 60 %(50 % V∞, L_CMOS=15 pF, f∞125 MHz/-20 °C to +70 °C)	ST OE ST	
	PC SC	28 m.A Max.	3.0 V to 3.6 V (2.7 V to 3.6 V)	15 pF (f ₀≤66.7 MHz/2.7 to 3.6 V)	3.0 ns Max. (20 % Vcc to 80 % Vcc, L_CMOS=Max.)	40 % to 60 % 050 % Voc, L_CMOS=15 pF, Voc=3.0 V to 3.6 V, fics40 MHz) 40 % to 60 % foc % Voc, L_CMOS=15 pF, Voc=3.0 V to 3.6 V, fics40 MHz) 1 (50 % Voc, L_CMOS=15 pF, Voc=3.0 V to 3.6 V, fics66.7 MHz)	OE ST	

► TABLE OF FREQUENCY RANGE

Model		Supply voltage	Frequency tolerance Operating Temperature	Frequency 1	y MHz	50 MHz	100 M Hz	125 MHz
	PT/ST	4.5 V to 5.5 V	B,C	1.0 MHz				125 MHz
SG-8002CE	PH/ SH	4.5 V 10 5.5 V	М	1.0 MHz		27 MHz		
30-0002CE	PC/SC	3.0 V to 3.6 V (2.7 V to 3.6 V)	B,C,M	1.0 MHz	*2.7 \	/ to 3.6 V : 1.0 MHz t	o 66.7 MHz	125 MHz
	DUVOU	5.0 V±0.5 V	B,C	1.0 MHz			80 MH z	
	PH/ SH		M,L	1.0 MHz		27 MHz		
SG-8002LB	PC/SC	3.3 V±0.3 V	B,C,M,L	1.0 MHz	*2.7 V	′ to 3.6 V : 1.0 MHz to	0 66.7 MHz	125 MHz
	PT/ST		B,C	1.0 MHz				125 MHz
SG-8002JF	PH/ SH	4.5 V to 5.5 V	М	1.0 MHz		40 MHz		
5G-8002JF	PC SC	3.0 V to 3.6 V (2.7 V to 3.6 V)	B,C,M	1.0 MHz	*2.7 V	/ to 3.6 V : 1.0 MHz t	o 66.7 MHz	125 MHz
SG-8002CA	PT/ ST		B,C	1.0 MHz				125 MHz
SG-8002JA PH/SH	PH/ SH	4.5 V to 5.5 V	М	1.0 MHz		55 MHz		
SG-8002DB SG-8002DC	PC/SC	3.0 V to 3.6 V (2.7 V to 3.6 V)	B,C,M	1.0 MHz	*2.7 ∖	/ to 3.6 V : 1.0 MHz t	o 66.7 MHz	125 MHz
50 8002 10	PT/ ST PH/ SH	4.5 V to 5.5 V	B C	1.0 MHz				125 MHz
SG-8002JC	PC/SC	3.0 V to 3.6 V (2.7 V to 3.6 V)	B C	1.0 MHz	*2.7 V	/ to 3.6 V : 1.0 MHz t	o 66.7 MHz	125 MHz

Frequency tolerance : B:±50×10⁻⁶(-20 °C to +70 °C), C:±100×10⁻⁶ (-20 °C to +70 °C), M:±100×10⁻⁶ (-40 °C to +85 °C), L:±50×10⁻⁶ (-40 °C to +85 °C)



SG / HG-8002 series_ Jitter specifications and characteristics chart

■PLL-PLL connection

Because we use a PLL technology, there are a few cases that the jitter value will increase when SG-8002 is connected to another PLL-oscillator.

In our experience, we are unable to recommend these products for the applications such as telecom carrier use or analog video clock use. Please be careful checking in advance for these application (Jitter specification is Max.250 ps/CL=15 pF)

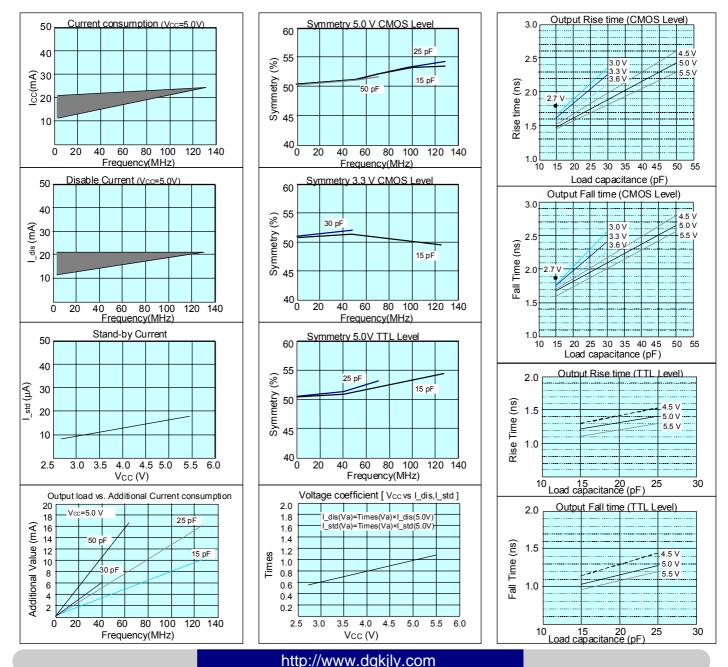
Jitter Specifications

Model	Supply Voltage	Jitter Item	Specifications	Remarks
	5.0 V ±0.5 V	Cycle to cycle	150 ps Max.	33 MHz \leq fo \leq 125 MHz, L_CMOS=15 pF
PT / PH			200 ps Max.	1.0 MHz \leq fo < 33 MHz, L CMOS=15 pF
ST / SH		Peak to peak	200 ps Max.	33 MHz \leq fo \leq 125 MHz, L_CMOS=15 pF
			250 ps Max.	1.0 MHz ≤ fo < 33 MHz, L_CMOS=15 pF
SC / PC	3.3 V ±0.3 V	Cycle to cycle	200 ps Max.	1.0 MHz \leq fo \leq 125 MHz, L_CMOS=15 pF
		5 5.5 V ±0.5 V	Peak to peak	250 ps Max.

Remarks on noise management for power supply line

We do not recommend inserting filters or other devices in the power supply line as the counter measure of EMI noise reduction. This device insertion might cause high-frequency impedance high in the power supply line and it affects oscillator stable drive. When this measure is required, please evaluate circuitry and device behavior in the circuit and verify that it will not affect oscillation. Start up time (0 % Vcc to 90 % Vcc) of power source should be more than 150 μ s.

■SG-8002 series Characteristics chart



"QMEMS" EPSON TOYOCOM

In order to meet customer needs in a rapidly advancing digital, broadband and ubiquitous society, we are committed to offering products that are one step ahead of the market and a rank above the rest in quality. To achieve our goals, we follow a "3D (three device) strategy" designed to drive both horizontal and vertical growth. We will to grow our three device categories of "Timing Devices", "Sensing Devices" and "Optical Devices", and expand vertical growth through a combination of products from these categories.

A Quartz MEMS is any high added value quartz device that exploits the characteristics of quartz crystal material but that is produced using MEMS (micro-electro-mechanical system) processing technology.

Market needs are advancing faster than previously imagined toward smaller, more stable crystal products, but we will stay ahead of the curve by rolling out products that exceed market speed and quality requirements. We want to further accelerate the 3D strategy by QMEMS. Quartz devices have become crucial in the network environment where products are increasingly intended for broadband, ubiquitous applications and where various types of terminals can transfer information almost immediately via LAN and WAN on a global scale. Epson Toyocom Corporation addresses every single aspect within a network environment. The new corporation offers "Digital Convergence" solutions to problems arising with products for consumer use, such as, core network systems and automotive systems.



PROMOTION OF ENVIRONMENTAL MANAGEMENT SYSTEM CONFORMING TO INTERNATIONAL STANDARDS

At Epson Toyocom, all environmental initiatives operate under the Plan-Do-Check-Action(PDCA) cycle designed to achieve continuous improvements. The environmental management system (EMS) operates under the ISO 14001 environmental management standard.

ISO 14000 is an international standard for environmental management that was established by the International Standards Organization in 1996 against the background of growing concern regarding global warming, destruction of the ozone laver and global deforestation

All of our major manufacturing and non-manufacturing sites, in Japan and overseas, completed the acquisition of ISO 14001 certification. In the future, new group companies will be expected to acquire the certification around the third year of operations.

WORKING FOR HIGH QUALITY

In order provide high quality and reliable products and services than meet customer needs,

Epson Toyocom made early efforts towards obtaining ISO9000 series certification and has acquired ISO9001 for all business establishments in Japan and abroad. We have also acquired ISO/TS 16949 certification that is requested strongly by major automotive manufacturers as standard.

QS-9000 is an enhanced standard for quality assurance systems formulated by leading U.S. automobile manufacturers based on the international ISO 9000 series.

 $\rm ISO/TS$ 16949 is a global standard based on QS-9000, a severe standard corresponding to the requirements from the automobile industry.

Explanation of the mark that are using it for the catalog

Pb Free	 ▶ Pb free. ▶ Complies with EU RoHS directive.
Rolls	 Pb free terminal designed. Contains Pb in products exempted by RoHS directive. (Contains Pb in sealing glass, high melting temperature type solder or other.) Complies with EU RoHS directive.
For Automotive	► The products have been designed for high reliability applications such as Automotive.

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- / Medical instruments to sustain life / Submarine transmitters / Power stations and related / Fire work equipment and security equipment / traffic control equipment / and others requiring equivalent reliability.
- In this new crystal master for Epson Toyocom, product codes and markings will remain as previously identified prior to the merger. Due to the on-going strategy of gradual unification of part numbers, please review product codes and markings, as they will change during the course of the coming months.

We apologize for the inconvenience, but we will eventually have a unified part numbering system for Epson Toyocom that will be user friendly.